

SNx5175 四路差分线路接收器

1 特性

- 符合或超出 ANSI 标准 EIA/TIA-422-B、RS-423-B 和 RS-485 的要求
- 符合 ITU 建议 V.10、V.11、X.26 和 X.27 的要求
- 适用于嘈杂环境中长总线上的多点总线传输
- 三态输出
- 共模输入电压范围：-12V 至 12V
- 输入灵敏度：±200mV
- 输入迟滞：50mV (典型值)
- 高输入阻抗：12kΩ (最小值)
- 由 5V 单电源供电
- 低功耗要求
- MC3486 的插入式替代产品

2 应用

- 电机驱动器
- 工厂自动化和控制

3 说明

SN65175 和 SN75175 是具有三态输出的单片四路差分线路接收器。这些器件符合 ANSI 标准 EIA/TIA-422-B、RS-423-B 和 RS-485 以及数项 ITU 建议的要求。这些标准适用于速率高达 10 兆位/秒的平衡多点总线传输。两对接收器中的每一对都具有一个共用的高电平有效使能端。

这些接收器具有高输入阻抗、用于提高抗噪性的输入迟滞、以及在 ±12V 共模输入电压范围内 ±200mV 的输入灵敏度。SN65175 和 SN75175 与 SN75172 或 SN75174 四路差分线路驱动器配合使用时，可实现卓越性能。

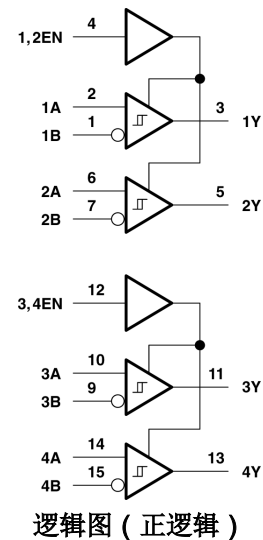
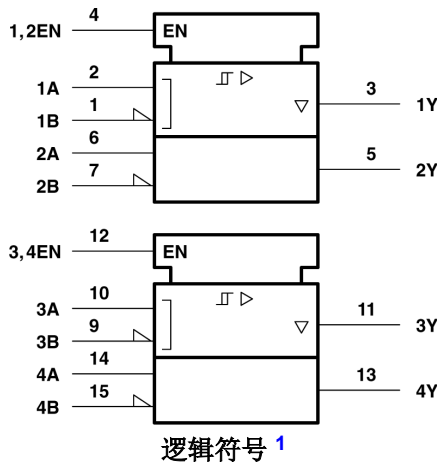
SN65175 的额定工作温度范围为 -40°C 至 85°C。
SN75175 的额定工作温度范围为 0°C 至 70°C。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
SN65175	D (SOIC, 16)	9.9mm × 6mm
SN75175	N (PDIP, 16)	19.3mm × 9.4mm
	D (SOIC, 16)	9.9mm × 6mm
	NS (SOP, 16)	10.2mm × 7.8mm

(1) 有关所有详细信息，请参阅节 11。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。



¹ 此符号符合 ANSI/IEEE 标准 91-1984 和 IEC 出版物 617-12。



Table of Contents

1 特性	1	7 Detailed Description	11
2 应用	1	7.1 Device Functional Modes.....	11
3 说明	1	8 Application and Implementation	12
4 Pin Configuration and Functions	3	8.1 Application Information.....	12
5 Specifications	4	9 Device and Documentation Support	13
5.1 Absolute Maximum Ratings.....	4	9.1 接收文档更新通知.....	13
5.2 Dissipation Rating.....	4	9.2 支持资源.....	13
5.3 Recommended Operating Conditions.....	4	9.3 Trademarks.....	13
5.4 Thermal Information.....	5	9.4 静电放电警告.....	13
5.5 Electrical Characteristics.....	5	9.5 术语表.....	13
5.6 Switching Characteristics.....	6	10 Revision History	13
5.7 Typical Characteristics.....	7	11 Mechanical, Packaging, and Orderable Information	13
6 Parameter Measurement Information	9		

4 Pin Configuration and Functions

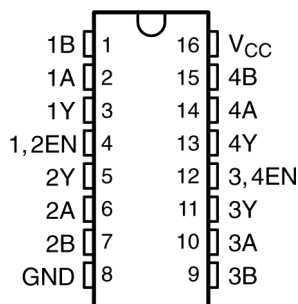


图 4-1. D, N, or NS Package (Top View)

表 4-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
1B	1	I	Channel 1 Differential Receiver Inverting Input
1A	2	I	Channel 1 Differential Receiver Non-Inverting Input
1Y	3	O	Channel 1 Single Ended Output
1,2EN	4	I	Active High Enable for Channels 1 and 2
2Y	5	O	Channel 2 Single Ended Output
2A	6	I	Channel 2 Differential Receiver Non-Inverting Input
2B	7	I	Channel 2 Differential Receiver Inverting Input
GND	8	GND	Device GND
3B	9	I	Channel 3 Differential Receiver Inverting Input
3A	10	I	Channel 3 Differential Receiver Non-Inverting Input
3Y	11	O	Channel 3 Single Ended Output
3,4EN	12	I	Active High Enable for Channels 3 and 4
4Y	13	O	Channel 4 Single Ended Output
4A	14	I	Channel 4 Differential Receiver Non-Inverting Input
4B	15	I	Channel 4 Differential Receiver Inverting Input
V _{CC}	16	PWR	Device V _{CC} (4.75 V to 5.25 V)

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIX	MAX	UNIT
V_{CC} ⁽²⁾	Supply voltage			7	V
V_I	Input voltage (A or B inputs)			±25	V
V_{ID} ⁽³⁾	Differential input voltage			±25	V
$V_{I(EN)}$	Enable input voltage			7	V
I_{OL}	Low-level output current			50	mA
	Continuous total dissipation	See Dissipation Rating table			
T_A	Operating free-air temperature range:	SN65175	–40	85	°C
		SN75175	0	70	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds			260	°C
T_{stg}	Storage temperature range		–65	150	°C

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential input voltage, are with respect to network ground terminal.
- (3) Differential-input voltage is measured at the noninverting input with respect to the corresponding inverting input.

5.2 Dissipation Rating

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW	494 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
Common-mode input voltage, V_{IC}				±12	V
Differential input voltage, V_{ID}				±12	V
High-level enable-input voltage, V_{IH}		2			V
Low-level enable-input voltage, V_{IL}				0.8	V
High-level output current, I_{OH}				–400	µA
Low-level output current, I_{OL}				16	mA
Operating free-air temperature, T_A	SN65175	–40		85	°C
	SN75175	0		70	

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		D (SOIC)	N (PDIP)	NS (SOP)	UNIT
		16-PINS			
R _{θJA}	Junction-to-ambient thermal resistance	84.6	60.6	88.5	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	43.5	48.1	46.2	°C/W
R _{θJB}	Junction-to-board thermal resistance	43.2	40.6	50.7	°C/W
ψ _{JT}	Junction-to-top characterization parameter	10.4	27.5	13.5	°C/W
ψ _{JB}	Junction-to-board characterization parameter	42.8	40.3	50.3	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.5 Electrical Characteristics

over recommended ranges of common-mode input voltage, supply voltage and operating free-air temperature

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage	$V_O = 2.7\text{ V}$,	$I_O = -0.4\text{ mA}$			0.2	V
V_{IT-}	Negative-going input threshold voltage	$V_O = 0.5\text{ V}$,	$I_O = 16\text{ mA}$	-0.2 ⁽²⁾			V
V_{hys}	Hysteresis voltage ($V_{IT+} - V_{IT-}$)	See 图 5-1			50		mV
V_{IK}	Enable-input clamp voltage	$I_I = -18\text{ mA}$				-1.5	V
V_{OH}	High-level output voltage	$V_{ID} = 200\text{ mV}$,	$I_{OH} = -400\text{ }\mu\text{A}$, See 图 6-1	2.7			V
V_{OL}	Low-level output voltage	$V_{ID} = -200\text{ mV}$,	See 图 6-1 $I_{OL} = 8\text{ mA}$			0.45	V
			$I_{OL} = 16\text{ mA}$			0.5	
I_{OZ}	High-impedance-state output current	$V_O = 0.4\text{ V to }2.4\text{ V}$				± 20	μA
I_I	Line input current	Other input at 0 V, See (4)	$V_I = 12\text{ V}$			1	mA
			$V_I = -7\text{ V}$			-0.8	
I_{IH}	High-level enable-input current	$V_{IH} = 2.7\text{ V}$				20	μA
I_{IL}	Low-level enable-input current	$V_{IL} = 0.4\text{ V}$				-100	μA
r_i	Input resistance			12			k Ω
I_{OS}	Short-circuit output current ⁽³⁾			-15		-85	mA
I_{CC}	Supply current	Outputs disabled				70	mA

- (1) All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.
(2) The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for threshold voltage levels only.
(3) Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.
(4) Refer to ANSI Standards EIA/TIA-422-B, RS-423-B, and RS-485 for exact conditions.

5.6 Switching Characteristics

$V_{CC} = 5\text{ V}$, $C_L = 15\text{ pF}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	See 图 6-2		22	35	ns
t_{PHL}	Propagation delay time, high- to low-level output			25	35	ns
t_{PZH}	Output enable time to high level	See 图 6-3		13	30	ns
t_{PZL}	Output enable time to low level			19	30	ns
t_{PHZ}	Output disable time from high level	See 图 6-3		26	35	ns
t_{PLZ}	Output disable time from low level			25	35	ns

5.7 Typical Characteristics

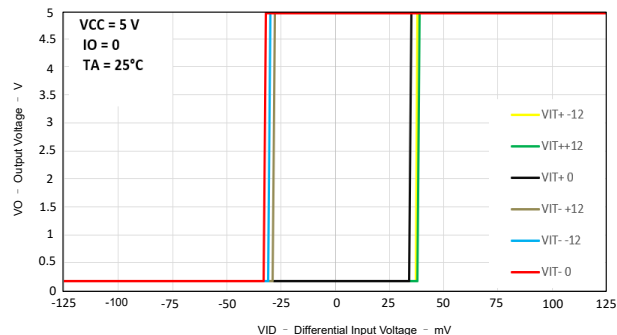


图 5-1. Output Voltage vs Differential Input Voltage

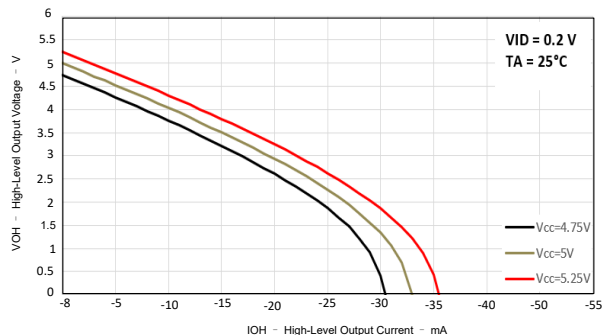


图 5-2. High-level Output Voltage vs High-level Output Current

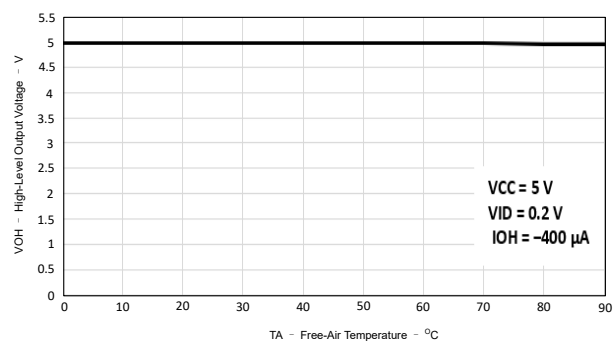


图 5-3. High-level Output Voltage vs Free-air Temperature

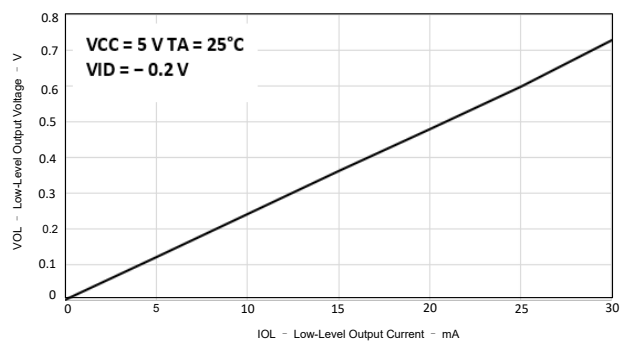


图 5-4. Low-level Output Voltage vs Low-level Output Current

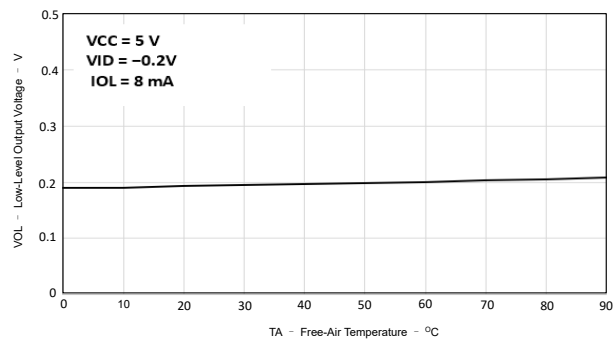


图 5-5. Low-level Output Voltage vs Free-air Temperature

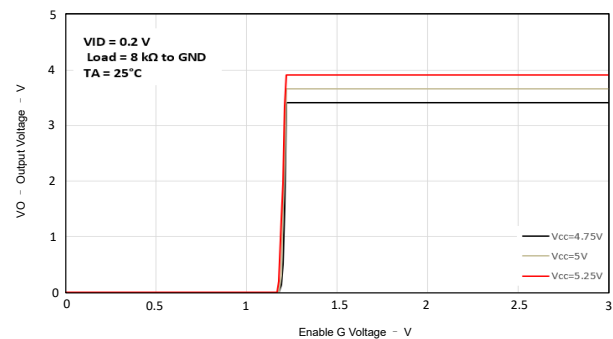


图 5-6. Output Voltage vs Enable G Voltage

5.7 Typical Characteristics (continued)

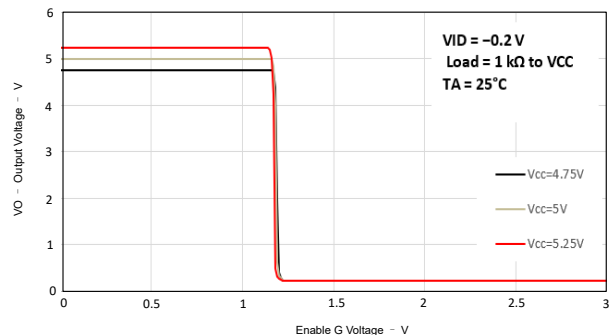


图 5-7. Output Voltage vs Enable G Voltage

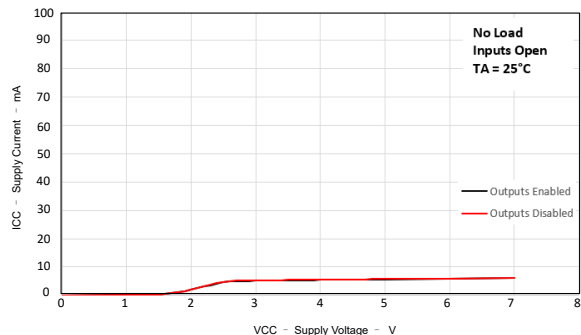


图 5-8. Supply Current (All Receivers) vs Supply Voltage

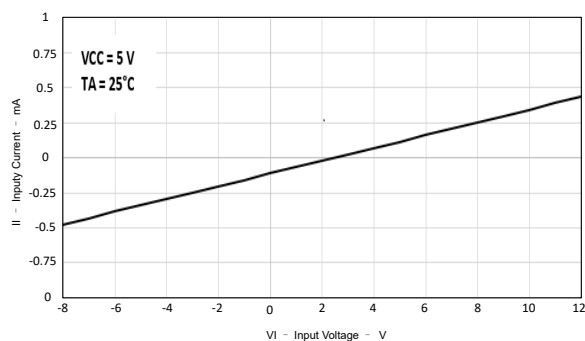


图 5-9. Input Current vs Input Voltage

6 Parameter Measurement Information

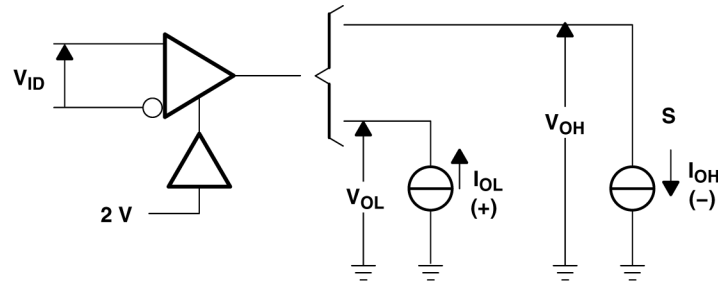
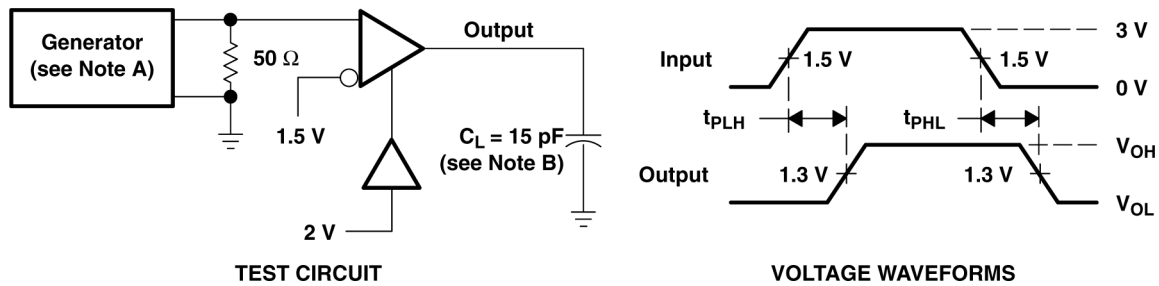


图 6-1. V_{OH} , V_{OL}

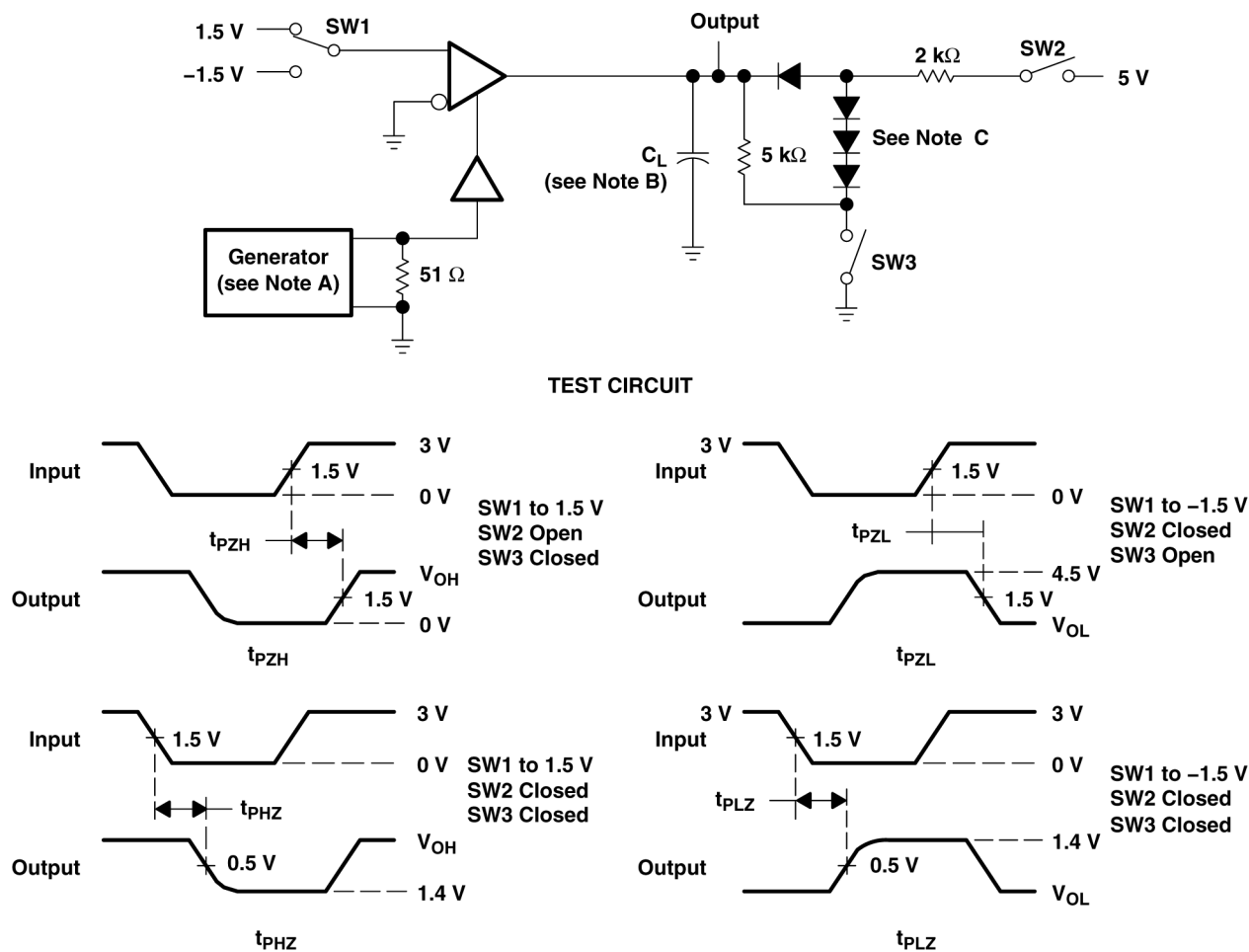


TEST CIRCUIT

VOLTAGE WAVEFORMS

- A. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1 \text{ MHz}$, duty cycle = 50%, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$, $Z_O = 50 \Omega$.
- B. C_L includes probe and stray capacitance.

图 6-2. Test Circuit and Voltage Waveforms



- A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle = 50%, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
- B. C_L includes probe and stray capacitance.
- C. All diodes are 1N916 or equivalent.

图 6-3. Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Device Functional Modes

表 7-1. Function Table (Each Receiver)

DIFFERENTIAL A – B ⁽¹⁾	ENABLE	OUTPUT Y
$V_{ID} \geq 0.2 \text{ V}$	H	H
$-0.2 \text{ V} < V_{ID} < 0.2 \text{ V}$	H	?
$V_{ID} \leq -0.2 \text{ V}$	H	L
X	L	Z
Open circuit	H	?

(1) H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

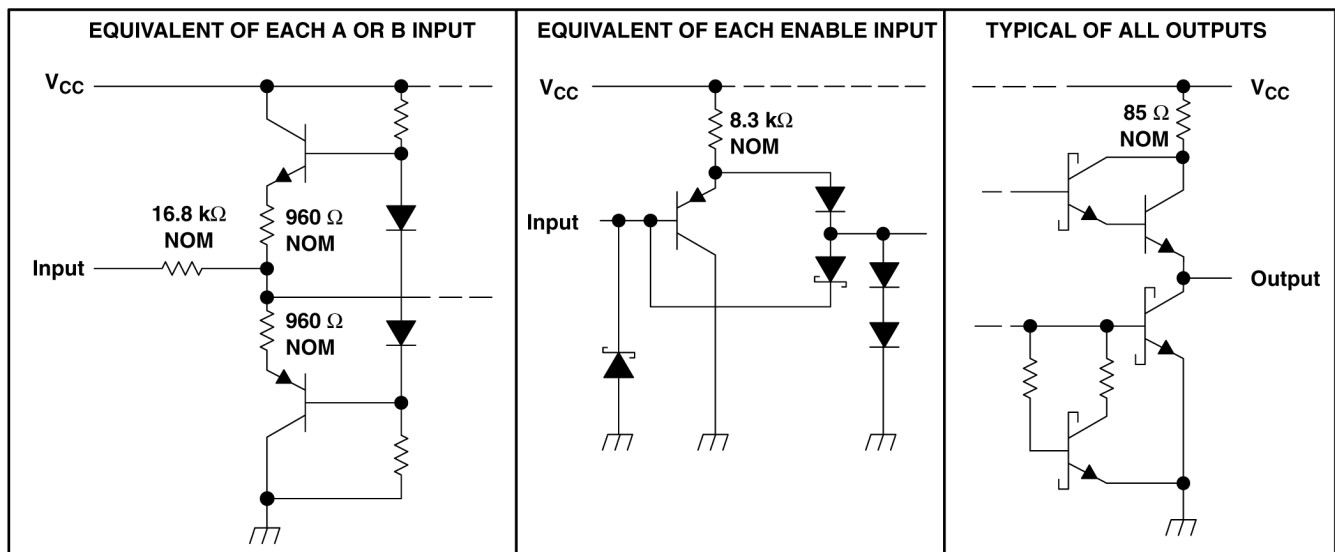


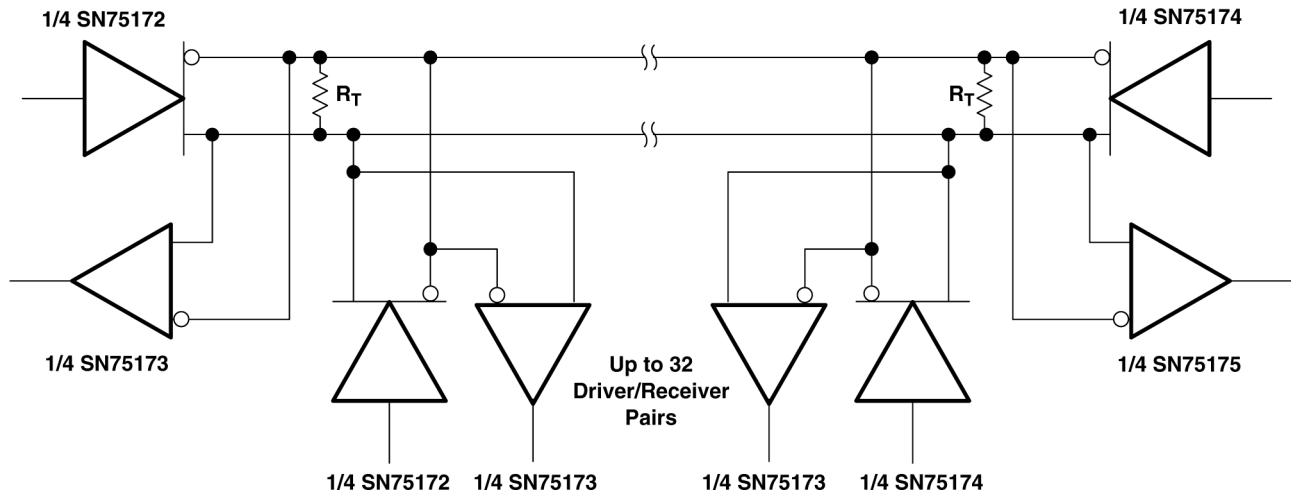
图 7-1. Schematics of Inputs and Outputs

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information



- A. The line should be terminated at both ends in its characteristic impedance ($R_T = Z_0$). Stub lengths off the main line should be kept as short as possible.

图 8-1. Typical Application Circuit

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.2 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《[使用条款](#)》。

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
所有商标均为其各自所有者的财产。

9.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.5 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision C (November 2006) to Revision D (October 2023)	Page
• 更改了整个文档中的表格、图和交叉参考的编号格式.....	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65175D	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN65175D.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN65175DR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN65175DR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	SN65175
SN75175D	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	0 to 70	SN75175
SN75175DR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175DR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175N	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75175N
SN75175N.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	SN75175N
SN75175NSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175NSR.A	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175
SN75175NSRG4	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75175

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75175DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75175NSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65175DR	SOIC	D	16	2500	353.0	353.0	32.0
SN75175DR	SOIC	D	16	2500	353.0	353.0	32.0
SN75175NSR	SOP	NS	16	2000	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN65175D	D	SOIC	16	40	507	8	3940	4.32
SN65175D.A	D	SOIC	16	40	507	8	3940	4.32
SN75175N	N	PDIP	16	25	506	13.97	11230	4.32
SN75175N.A	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



14/18 Pin Only
20 Pin vendor option

4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.



PACKAGE OUTLINE

NS0016A

SOP - 2.00 mm max height

SOP



4220735/A 12/2021

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.

EXAMPLE BOARD LAYOUT

NS0016A

SOP - 2.00 mm max height

SOP



SOLDER MASK DETAILS

4220735/A 12/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
 BASED ON 0.125 mm THICK STENCIL
 SCALE:7X

4220735/A 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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